

de Haas-van Alphen effect in CeCoIn₅ and CeRhIn₅ under pressure

H. Shishido¹, R. Settai¹, T. Kubo¹, S. Hashimoto¹, T. Ueda¹, H. Harima² and Y. Ōnuki¹

1 - Department of Physics, Graduate School of Science, Osaka University,
Toyonaka, Osaka, 560-0043, Japan

2 - The Institute of Scientific and Industrial Research, Osaka University,
Ibaraki, Osaka 567-0047, Japan

We have studied de Haas-van Alphen (dHvA) effect under pressure for a pressure-induced superconductor CeRhIn₅ and a heavy Fermion superconductor CeCoIn₅. These Fermi surfaces are cylindrical. The Fermi surface of CeRhIn₅ is almost the same as that of LaRhIn₅ at ambient pressure [1]. On the other hand, the 4*f* electron is itinerant in CeCoIn₅[2].

The Fermi surfaces in CeRhIn₅ and CeCoIn₅ are found to be unchanged up to 2.1 GPa and 3.1 GPa, respectively. The cyclotron effective mass of CeRhIn₅, however, increases with increasing pressure. For example, the cyclotron mass of branch β_2 ($m_c^* = 5.7 m_0$ at ambient pressure) reaches $40 m_0$ at 2 GPa, as shown in Fig. 1 (a)[3]. On the other hand, the cyclotron mass in CeCoIn₅, decreases with increasing pressure. The cyclotron mass of branch β_2 ($58 m_0$ at ambient pressure) decreases down to $38 m_0$ at 3 GPa, as shown in Fig. 1 (a)[4].

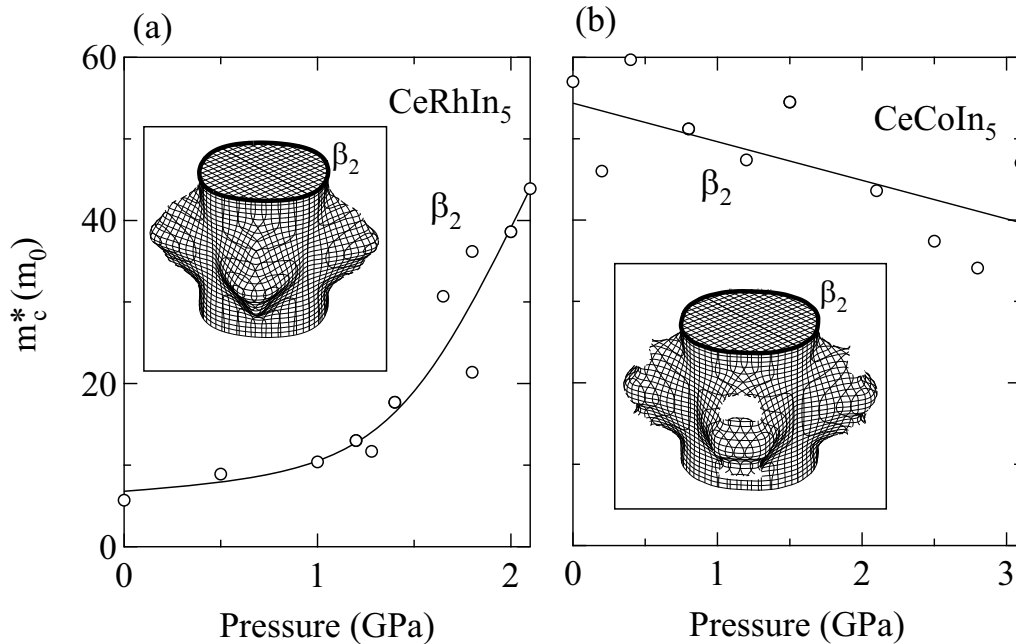


Figure 1: Pressure dependence of the cyclotron mass of branch β_2 in (a) CeRhIn₅ and (b) CeCoIn₅. The inset shows the Fermi surface corresponding branch β_2 .

[1] H. Shishido, R. Settai, D. Aoki, S. Ikeda, H. Nakawaki, T. Iizuka, Y. Inada, K. Sugiyama, T. Takeuchi, K. Kindo, T. C. Kobayashi, Y. Haga, H. Harima, Y. Aoki, T. Namiki, H. Sato and Y. Ōnuki: J. Phys. Soc. Jpn **71**, 162 (2002).

[2] R. Settai, H. Shishido, S. Ikeda, Y. Murakawa, M. Nakashima, D. Aoki, Y. Haga, H. Harima and Y. Ōnuki: J. Phys.: Condens. Matter **13**, L627 (2001).

[3] H. Shishido, T. Ueda, S. Hashimoto, T. Kubo, R. Settai, H. Harima and Y. Ōnuki: J. Phys.: Condens. Matter **15** L499 (2003).

[4] H. Shishido, R. Settai, S. Araki, T. Ueda, Y. Inada, T. C. Kobayashi, T. Muramatsu, Y. Haga and Y. Ōnuki: Phys. Rev. B **66** 214510 (2002).